NSN 5961-01-022-9220

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-022-9220 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches Thread Size: 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 12.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 2.5 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 10001-2855522 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: